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# **Novel In-Plane Semiconductor Lasers XV**

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**Peter M. Smowton**

*Editors*

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# Contents

vii	Authors
ix	Conference Committee

---

## STRUCTURE AND CAVITY DEVELOPMENTS

---

- 9767 03 **Type-I QW cascade diode lasers for spectral region above 3  $\mu\text{m}$  [9767-2]**
- 9767 05 **Generation of 7W nanosecond pulses with 670nm ridge-waveguide lasers [9767-4]**
- 9767 06 **GaAs-based self-aligned stripe superluminescent diodes processed normal to the cleaved facet [9767-5]**

---

## MATERIALS DEVELOPMENTS

---

- 9767 09 **Microscopic modelling of opto-electronic properties of dilute bismide materials for the mid-IR [9767-8]**
- 9767 0A **First demonstration of orange-yellow light emitter devices in InGaP/InAlGaP laser structure using strain-induced quantum well intermixing technique [9767-9]**

---

## BLUE/GREEN EMITTERS

---

- 9767 0C **Room-temperature continuous-wave operation of BeZnCdSe quantum-well green-to-yellow laser diodes with sub-10 mA threshold current [9767-11]**
- 9767 0E **Studies on 405nm blue-violet diode laser with external grating cavity [9767-13]**
- 9767 0F **Large TE polarized optical gain from AlInN-delta-GaN quantum well for ultraviolet lasers [9767-14]**

---

## QUANTUM DOTS

---

- 9767 0I **1.5 $\mu\text{m}$  quantum dot laser material with high temperature stability of threshold current density and external differential efficiency [9767-17]**
- 9767 0J **High-temperature continuous wave operation (up to 100°C) of InAs/InGaAs quantum dot electrically injected microdisk lasers [9767-18]**
- 9767 0L **High-speed directly modulated 1.5 $\mu\text{m}$  quantum dot lasers [9767-20]**

---

## CAVITY EFFECTS AND MODE-LOCKING

---

- 9767 0N **Timing jitter performance of mode-locked external cavity multi-quantum-well semiconductor lasers** [9767-22]
- 9767 0O **Interaction of phase and amplitude shaping in an external cavity semiconductor laser** [9767-23]

---

## DFB AND DBRs

---

- 9767 0Q **Narrow-linewidth 1.5 $\mu$ m quantum dot distributed feedback lasers** [9767-25]
- 9767 0R **Pulsed hybrid dual wavelength Y-branch-DFB laser-tapered amplifier system suitable for water vapor detection at 965 nm with 16 W peak power** [9767-26]
- 9767 0S **Difference frequency modulation of multi-section dual-mode lasers with nanoscale surface gratings** [9767-27]
- 9767 0T **5,000 h reliable operation of 785nm dual-wavelength DBR-RW diode lasers suitable for Raman spectroscopy and SERDS** [9767-28]
- 9767 0U **First demonstration of single-mode distributed feedback type-I GaSb cascade diode laser emitting near 2.9  $\mu$ m** [9767-29]

---

## LASERS ON SILICON

---

- 9767 0Y **Cavity enhanced 1.5 $\mu$ m LED with silicon as a hole injector** [9767-33]
- 9767 10 **Photonic-crystal lasers on silicon for chip-scale optical interconnects (Invited Paper)** [9767-35]

---

## INTERBAND AND QUANTUM CASCADE LASERS

---

- 9767 12 **Interband cascade laser sources in the mid-infrared for green photonics** [9767-37]
- 9767 13 **Step-taper active-region quantum cascade lasers for carrier-leakage suppression and high internal differential efficiency** [9767-38]
- 9767 14 **Surface-emitting quantum cascade laser with 2nd-order metal-semiconductor gratings for single-lobe emission** [9767-39]

---

## QCLs: COMBS AND MODE-LOCKING II

---

- 9767 1A **Frequency comb operation of long-cavity terahertz quantum-cascade lasers (Invited Paper)** [9767-45]

---

## NEW DEVICE CONCEPTS

---

- 9767 1E **Quantum dots as active material for quantum cascade lasers: comparison to quantum wells** [9767-50]

---

## HIGH-BRIGHTNESS LASERS

---

- 9767 1I **DBR tapered diode laser at 1030 nm with nearly diffraction-limited narrowband emission and 12.7 W of optical output power** [9767-53]
- 9767 1J **High performances of very long (13.5mm) tapered laser emitting at 975 nm** [9767-54]
- 9767 1K **Three-section master oscillator power amplifier at 1.57  $\mu\text{m}$  for lidar measurements of atmospheric carbon dioxide** [9767-55]
- 9767 1L **Novel approaches to increasing the brightness of broad area lasers (Invited Paper)** [9767-56]

---

## QCLs: CAVITIES, INTEGRATION, AND APPLICATIONS

---

- 9767 1R **Monolithic integration of a quantum cascade laser array and an echelle grating multiplexer for widely tunable mid-infrared sources** [9767-62]
- 9767 1S **Regrowth-free mid-infrared distributed feedback quantum cascade lasers with sub-watt power consumption** [9767-63]
- 9767 1T **Spectroscopic benzene detection using a broadband monolithic DFB-QCL array** [9767-64]
- 9767 1U **Cascade laser applications: trends and challenges** [9767-65]
- 9767 1V **Single-mode enhancement in coupled-cavity quantum cascade lasers** [9767-66]

---

## POSTER SESSION

---

- 9767 1W **Simulation of broad spectral bandwidth emitters at 1060 nm for optical coherence tomography** [9767-67]
- 9767 2I **Three-dimensional finite-difference time-domain modelling of photonic crystal surface-emitting lasers** [9767-72]



# Authors

Numbers in the index correspond to the last two digits of the six-digit citation identifier (CID) article numbering system used in Proceedings of SPIE. The first four digits reflect the volume number. Base 36 numbering is employed for the last two digits and indicates the order of articles within the volume. Numbers start with 00, 01, 02, 03, 04, 05, 06, 07, 08, 09, 0A, 0B...0Z, followed by 10-1Z, 20-2Z, etc.

Abautret, Johan, 1R	Feng, Jijun, 0C
Abdollahinia, Alireza, 0I, 0L	Feng, T., 03
Aho, Antti T., 0S	Fischer, M., 12
Akimoto, Ryoichi, 0C	Forouhar, Siamak, 0U, 1S
Alias, Mohd S., 0A	Fradet, Mathieu, 0U, 1S
Al-Jabr, Ahmad A., 0A	Frez, Clifford, 0U, 1S
Alnahhas, Bayan A., 0A	Fricke, Jörg, 05, 1I, 1L
Anjum, Dalaver H., 0A	Fujii, Takuro, 10
Babazadeh, N., 06	G. Tijero, José Manuel, 1K
Badescu, S. C., 09	Gao, Jun, 0E
Balzer, Jan C., 0O	Garcia, M., 1J
Banyoudeh, Saddam, 0I, 0L	Ghazal, O. M. S., 06
Baum, Philipp, 0Q	Gilles, Clément, 1R
Becker, Annette, 0Q	Grahn, H. T., 1A
Becker, S., 12	Groom, K. M., 06, 1W
Belenky, Gregory, 03, 0U	Hader, J., 09
Bjelica, Marko, 0Q	Hasebe, Koichi, 10
Blanchard, Romain, 1S	Heinrich, W., 05
Boiko, D. L., 1J	Hoffmann, Thomas, 05, 0R
Botez, D., 13, 14	Höfling, S., 12
Boyle, C., 13, 14	Hofmann, Martin R., 0N, 0O
Brenner, Carsten, 0N, 0O	Hogg, Richard A., 06, 1W, 21
Briggs, Ryan M., 1S	Horstkemper, Heiko, 0N
Brox, Olaf, 1I	Hosoda, Takashi, 03, 0U
Bugajski, M., 1V	Ivanov, Pavlo, 21
Bugge, Frank, 1I	Johnson, S., 09
Carpintero, Guillermo, 1R	Kakitsuka, Takaaki, 10
Carras, Mathieu, 1R	Kamp, M., 12
Chang, C.-C., 13	Khamas, Salam, 21
Chang, Tzu-Hsuan, 0Y	Kim, Munho, 0Y
Childs, David T. D., 06, 1W, 21	Kipshidze, G., 03
Cho, SangJune, 0Y	Kirch, J. D., 13, 14
Chow, Weng W., 1E	Klehr, Andreas, 05, 0N, 0O, 0R
Crump, P., 1L	Knigge, S., 1L
Czyszanowski, T., 1V	Koch, S. W., 09
Decker, J., 1L	Koeth, J., 12
d'Humières, B., 1U	Krakowski, Michel, 1J, 1K
Döpke, Benjamin, 0N, 0O	Kryzhanovskaya, N. V., 0J
Dumitrescu, Mihail, 0S	Kuc, M., 1V
Earles, T., 13, 14	Kudashova, Yu. V., 0J
Eisenstein, Gadi, 0L, 0Q	Kulagina, M. M., 0J
Ekterai, M., 1L	Kuramochi, Eiichi, 10
Elafandy, Rami T., 0A	Lecomte, M., 1J
Erbert, Götz, 05, 0N, 0O, 1I, 1L	Lee, Jaeseong, 0Y
Erdelyi, Robertus, 21	Lei, D., 06
Esquivias, Ignacio, 1K	Lewicki, Rafat, 1T
Eyal, Ori, 0L, 0Q	Li, Biao, 1T
Faugeron, Mickael, 1K	Li, Bin, 0E
Fazilleau, Yves, 1U	Li, Guangrui, 21

- Liero, Armin, 05, 0R  
 Lindberg, D., III, 13, 14  
 Liu, Cheng, 0F  
 Liu, Dong, 0Y  
 Livshits, D. A., 0J  
 Luo, Shiwen, 0E  
 Ma, Zhenqiang, 0Y  
 Maaßdorf, A., 1L  
 Maisons, Grégory, 1R  
 Maiwald, Martin, 0T  
 Majid, Mohammed A., 0A  
 Margoto, Éric, 1U  
 Matsuo, Shinji, 10  
 Mawst, L. J., 13, 14  
 Maximov, M. V., 0J  
 Michael, Stephan, 1E  
 Moiseev, E. I., 0J  
 Moloney, J. V., 09  
 Müller, André, 0T, 1I  
 Nähle, L., 12  
 Ng, Tien Khee, 0A  
 Notomi, Masaya, 10  
 Ooi, Boon S., 0A  
 Ooi, Yu Kee, 0F  
 Orbe, Luis J., 1R  
 Oubei, Hassan M., 0A  
 Parillaud, O., 1J  
 Pérez-Serrano, Antonio, 1K  
 Pflügl, Christian, 1S  
 Pilny, Rouven H., 0N, 0O  
 Pohl, J., 05  
 Prziwarka, T., 05  
 Reithmaier, Johann Peter, 0I, 0L, 0Q  
 Resneau, P., 1J  
 Rippien, Anna, 0Q  
 Röben, B., 1A  
 Robert, Y., 1J  
 Rubel, O., 09  
 Salmi, Joel, 0S  
 Sander, Stanley, 0U  
 Sarma, Jayanta, 21  
 Sarzała, R. P., 1V  
 Scheuermann, J., 12  
 Schnabel, Florian, 0L, 0Q  
 Schneider, Hans Christian, 1E  
 Schrottke, L., 1A  
 Seo, Jung-Hun, 0Y  
 Shehata, Mohamed, 0A  
 Shinya, Akihiko, 10  
 Shterengas, Leon, 03, 0U  
 Sichkovskyi, Vitalii, 0I, 0L, 0Q  
 Sigler, C., 14  
 Stevens, B. J., 06, 1W  
 Sumpf, Bernd, 0R, 0T, 1I  
 Takeda, Koji, 10  
 Taylor, Richard J. E., 21  
 Tooley, I. G., 1W  
 Tränkle, Günther, 0N, 0O, 0R  
 Troshkov, S. I., 0J  
 Uusitalo, Topi, 0S  
 Van Dijk, Frédéric, 1K  
 Viherälä, Jukka, 0S  
 Vilera, Mariafernanda, 1K  
 Vinet, E., 1J  
 Virtanen, Heikki, 0S  
 von Edlinger, M., 12  
 Vu, Thi N., 0R  
 Wang, M., 03  
 Wang, Xinbing, 0E  
 Wang, Xudong, 0Y  
 Weih, R., 12  
 Wenzel, H., 05  
 Wienold, M., 1A  
 Winterfeldt, M., 1L  
 Witinski, Mark, 1T  
 Witzigmann, Bernd, 0Q  
 Wünsche, H.-J., 05  
 Wysocki, Gerard, 1T  
 Xia, Zhenyang, 0Y  
 Xiong, Dongsheng, 0E  
 Yin, Xin, 0Y  
 Yu, Anlan, 0E  
 Zadiranov, Yu. M., 0J  
 Zhang, Hui long, 0Y  
 Zhang, Jing, 0F  
 Zhao, Deyin, 0Y  
 Zhao, Jun, 0E  
 Zhou, Weidong, 0Y  
 Zhukov, A. E., 0J  
 Zubov, F. I., 0J  
 Zuo, Duluo, 0E

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**Michael Kneissl**, Technische Universität Berlin (Germany)
- 4 Quantum Dots  
**Samuel Shultz**, Cardiff University (United Kingdom)
- 5 Cavity Effects and Mode-Locking  
**Luke F. Lester**, Virginia Polytechnic Institute and State University (United States)
- 6 DFB and DBRs  
**Koji Takeda**, NTT Device Technology Laboratories (Japan)
- 7 Lasers on Silicon  
**Haisheng Rong**, Intel Corporation (United States)
- 8 Interband and Quantum Cascade Lasers  
**Jerry R. Meyer**, U.S. Naval Research Laboratory (United States)
- 9 QCLs: Combs and Mode-Locking I  
**Sukhdeep Dhillon**, Laboratoire Pierre Aigrain (France)
- 10 QCLs: Combs and Mode-Locking II  
**Gustavo F. Villares**, ETH Zürich (Switzerland)
- 11 New Device Concepts  
**Andreas Wacker**, Lund Universitet (Sweden)
- 12 High-Brightness Lasers  
**Gary M. Smith**, MIT Lincoln Laboratory (United States)
- 13 Terahertz Quantum Cascade Lasers  
**Miriam Serena Vitiello**, Consiglio Nazionale delle Ricerche (Italy)
- 14 QCLs: Cavities, Integration, and Applications  
**Dan Botez**, University of Wisconsin-Madison (United States)